

Phase Control Thyristors (Hockey PUK Version), 960 A



E-PUK (TO-200AB)

PRIMARY CHARACTERISTICS						
I _{T(AV)} 960 A						
V_{DRM}/V_{RRM}	400 V, 600 V					
V_{TM}	1.58 V					
I _{GT}	100 mA					
T_J	-40 °C to +150 °C					
Package	E-PUK (TO-200AB)					
Circuit configuration	Single SCR					

FEATURES

- · Center amplifying gate
- Metal case with ceramic insulator
- International standard case E-PUK (TO-200AB)



- Extended temperature range
- Low profile hockey PUK to increase current-carrying capability
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	VALUES	UNITS				
1		960	A				
$I_{T(AV)}$	T _{hs}	80	°C				
1		2220	Α				
I _{T(RMS)}	T _{hs}	25	°C				
1	50 Hz	12 500	Δ.				
ITSM	60 Hz	13 000	A				
I ² t	50 Hz	782	kA ² s				
1-1	60 Hz	713	KA-S				
V _{DRM} /V _{RRM}		400 to 600	V				
t _q	Typical	100	μs				
T _J		-40 to 150	°C				

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE VDRM/VRRM, MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{aligned} I_{DRM}/I_{RRM}MAXIMUM\\ ATT_J = T_J\\ MAXIMUMmA \end{aligned}$					
VS-ST380CHC	04	400	500	100					
V 0 0 1 3 0 0 0 1 1 0	06	600	700	130					



ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL		TEST CONDITIONS			UNITS
Maximum average on-state current	L	180° condu	180° conduction, half sine wave		960 (440)	Α
at heatsink temperature	$I_{T(AV)}$	double side	(single side) co	oled	80 (110)	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	heatsink tempe	erature double side cooled	2220	
		t = 10 ms	No voltage		12 500	
Maximum peak, one-cycle non-repetitive surge current	ı	t = 8.3 ms	reapplied		13 000	A kA ² s
	I _{TSM}	t = 10 ms	100 % V _{RRM}		10 500	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	11 000	
	l ² t	t = 10 ms	No voltage reapplied	initial $T_J = T_J$ maximum	782	
		t = 8.3 ms			713	
Maximum I ² t for fusing		t = 10 ms			553	
		t = 8.3 ms	reapplied		505	
Maximum l²√t for fusing	I ² √t	t = 0.1 to 10	ms, no voltage	reapplied	7820	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$), $T_J = T_J$ maximum	0.85	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	(J) , $T_J = T_J$ maxin	num	0.88	V
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum			0
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.24	mΩ
Maximum on-state voltage	V_{TM}	$I_{pk} = 2900 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.58	V
Maximum holding current	I _H	T 05 °C	T _{.I} = 25 °C, anode supply 12 V resistive load		600	A
Typical latching current	ΙL	1 J = 25 °C,	anoue supply 1	z v resistive idad	1000	mA

SWITCHING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum non-repetitive rate of rise of turned-on current	dI/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/μs				
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1$ A/ μ s $V_d = 0.67 \% V_{DRM}$, $T_J = 25 \ ^{\circ}C$	1.0					
Typical turn-off time	t _q	I_{TM} = 550 A, T_J = T_J maximum, dl/dt = 40 A/μs, V_R = 50 V, dV/dt = 20 V/μs, gate 0 V 100 Ω , t_p = 500 μs	100	μs				

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs			
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	100	mA			



TRIGGERING							
PARAMETER	SYMBOL	TE	et conditione	VALUES		UNITS	
PARAMETER	STINIBUL	16	TEST CONDITIONS		MAX.	UNITS	
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10	0.0	w	
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2.	.0	VV	
Maximum peak positive gate current	I _{GM}	T _J = T _J maximum,	$t_p \le 5 \text{ ms}$	3.	.0	Α	
Maximum peak positive gate voltage	+ V _{GM}	T - T movimum	+ < 5 ma	2	0	V	
Maximum peak negative gate voltage	- V _{GM}	ij = ij maximum,	$T_J = T_J$ maximum, $t_p \le 5$ ms			7	
	I _{GT}	T _J = -40 °C		200	-		
DC gate current required to trigger		I _{GT}	T _J = 25 °C	Maximum required gate trigger/	100	200	mA
		T _J = 150 °C	current/voltage are the lowest value which will trigger all units	40	-		
		T _J = -40 °C		2.5	-		
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	12 V anode to cathode applied	1.8	3.0	٧	
		T _J = 150 °C		1.0	-		
DC gate current not to trigger	I _{GD}	T T	Maximum gate current/voltage not to trigger is the maximum	10		mA	
DC gate voltage not to trigger	V _{GD}	$T_J = T_J \text{ maximum}$	value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.25		V	

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum operating junction temperature range	TJ		-40 to 150	°C			
Maximum storage temperature range	T _{Stg}		-40 (0 150				
Maximum thermal resistance, junction to heateigh	В	DC operation single side cooled	0.09				
Maximum thermal resistance, junction to heatsink	R _{thJ-hs}	DC operation double side cooled	0.04	K/W			
Maximum thermal resistance, case to heatsink	R _{thC-hs}	DC operation single side cooled	0.02	10/00			
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.01				
Mounting force, ± 10 %			9800 (1000)	N (kg)			
Approximate weight			83	g			
Case style		See dimensions - link at the end of datasheet	E-PUK (TO-2	200AB)			

△R _{thJ-hs} CONDUCTION								
CONDUCTION ANGLE	SINUSOIDAL	CONDUCTION	RECTANGULAR	R CONDUCTION	TEGT COMPITIONS	UNITS		
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS		
180°	0.010	0.011	0.007	0.007				
120°	0.012	0.012	0.012	0.013				
90°	0.015	0.015	0.016	0.017	$T_J = T_J$ maximum	K/W		
60°	0.022	0.022	0.023	0.023				
30°	0.036	0.036	0.036	0.037				

Note

• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

www.vishay.com

Vishay Semiconductors

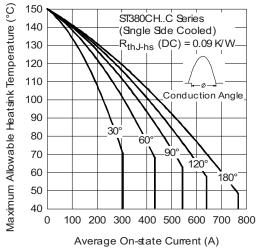


Fig. 1 - Current Ratings Characteristics

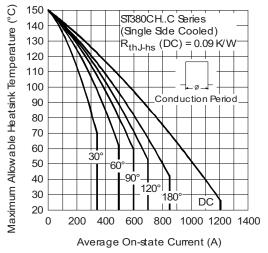


Fig. 2 - Current Ratings Characteristics

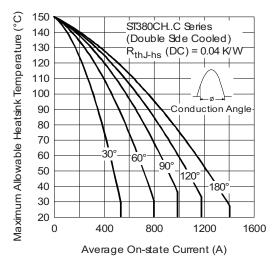


Fig. 3 - Current Ratings Characteristics

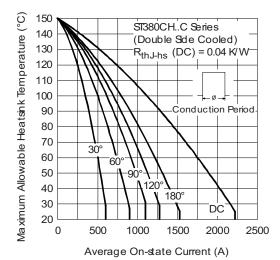


Fig. 4 - Current Ratings Characteristics

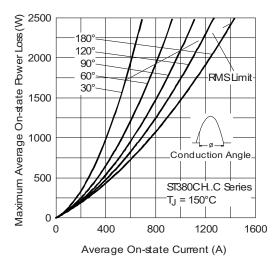


Fig. 5 - On-State Power Loss Characteristics

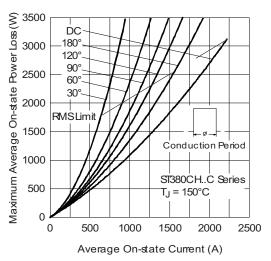


Fig. 6 - On-State Power Loss Characteristics

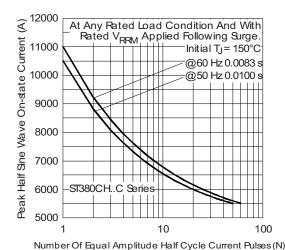


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

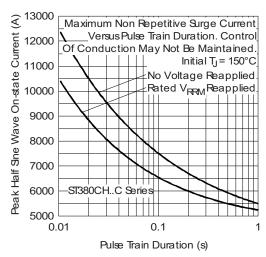


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

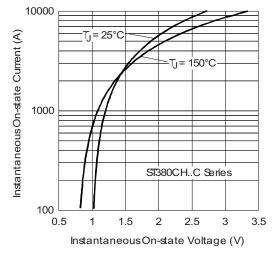


Fig. 9 - On-State Voltage Drop Characteristics

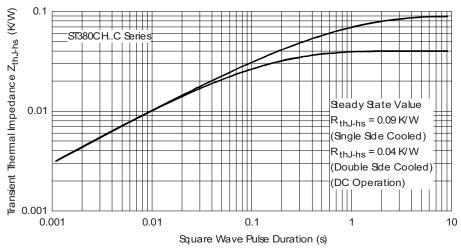


Fig. 10 - Thermal Impedance $Z_{\text{thJ-hs}}$ Characteristics

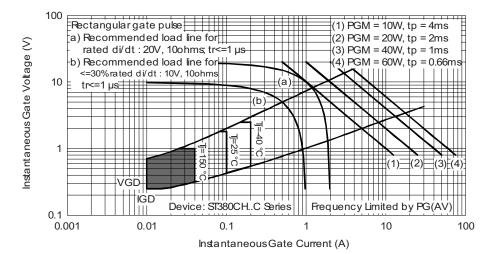


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	ST	38	0	СН	06	С	1	-
	1	2	3	4	5	6	7	8	9

1 - Vishay Semiconductors product

2 - Thyristor

3 - Essential part number

4 - 0 = converter grade

5 - CH = ceramic PUK, high temperature

6 - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

7 - C = PUK case E-PUK (TO-200AB)

8 - 0 = eyelet terminals (gate and auxiliary cathode unsoldered leads)

1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)

2 = eyelet terminals (gate and auxiliary cathode soldered leads)

3 = fast-on terminals (gate and auxiliary cathode soldered leads)

9 - Critical dV/dt: • None = 500 V/µs (standard selection)

• L = 1000 V/µs (special selection)

LINKS TO RELAT	ED DOCUMENTS
Dimensions	http://www.vishay.com/doc?95075

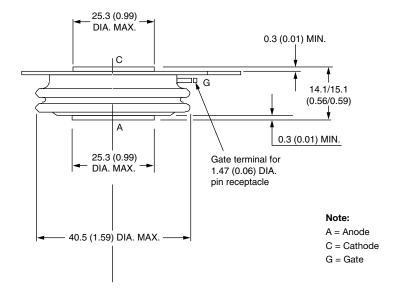


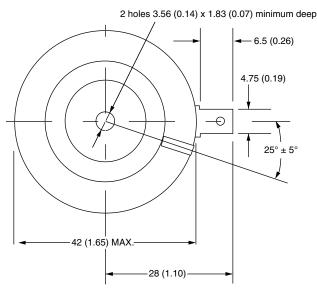
E-PUK (TO-200AB)

DIMENSIONS in millimeters (inches)

Anode to gate

Creepage distance: 11.18 (0.44) minimum Strike distance: 7.62 (0.30) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)

Legal Disclaimer Notice



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.